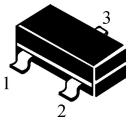
MMUN2132L

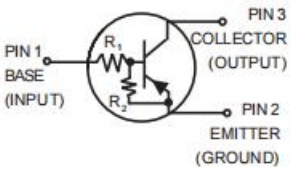
SOT-23 Digital Transistor 数字晶体管

■Features 特点

PNP With Bias Resistor Network
带偏置电阻

SOT—23
1. BASE
2. EMITTER
3. COLLECTOR





■Absolute Maximum Ratings 最大额定值

Characteristic 特性参数	Symbol 符号	Rat 额定值	Unit 单位
Collector-Base Voltage 集电极基极电压	V_{CBO}	-50	V
Collector-Emitter Voltage 集电极发射极电压	V_{CEO}	-50	V
Collector Current 集电极电流	I_C	-100	mA
Power dissipation 耗散功率	$P_C(T_a=25℃)$	246	mW
Thermal Resistance Junction-Ambient 热阻	$R_{\Theta JA}$	508	℃/W
Junction and Storage Temperature 结温和储藏温度	T_J,T_{stg}	-55to+150℃	

■Device Marking 产品打标

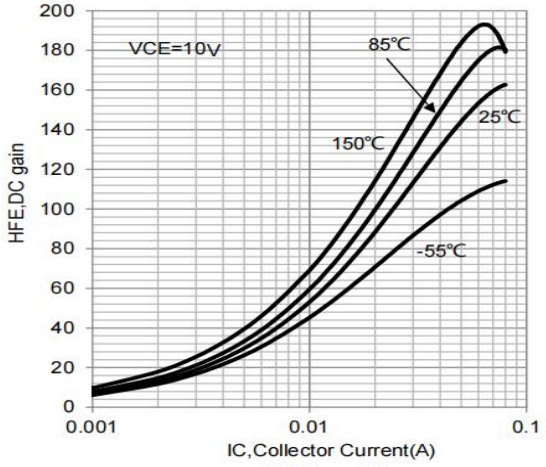
MMUN2132L=A6J

■Electrical Characteristics 电特性

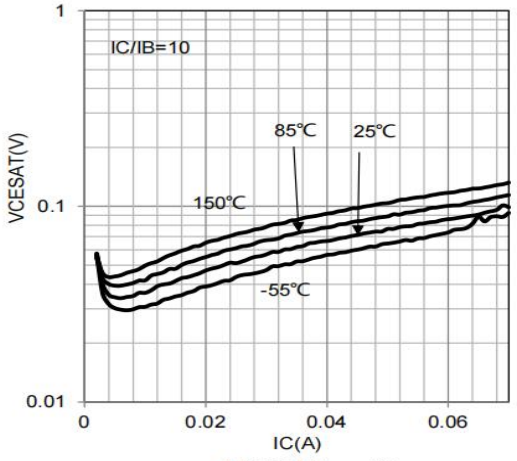
(T_A=25℃ unless otherwise noted 如无特殊说明，温度为 25℃)

Characteristic 特性参数	Symbol 符号	Min 最小值	Type 典型值	Max 最大值	Unit 单位
Collector-Base Breakdown Voltage 集电极基极击穿电压 (I_C= -10uA，I_E=0)	BV_{CBO}	-50	—	—	V
Collector-Emitter Breakdown Voltage 集电极发射极击穿电压 (I_C= -2mA，I_B=0)	BV_{CEO}	-50	—	—	V
Collector-Base Leakage Current 集电极基极漏电流 (V_{CB}= -50V，I_E=0)	I_{CBO}	—	—	-100	nA
Collector-Emitter Leakage Current 集电极发射极漏电流 (V_{CE}= -50V，I_E=0)	I_{CEO}	—	—	-500	nA
Emitter-Base Leakage Current 发射极基极漏电流 (V_{EB}= -6V，I_C=0)	I_{EBO}	—	—	-1.5	mA
DC Current Gain 直流电流增益 (V_{CE}= -10V，I_C= -5mA)	H_{FE}	15	27	—	
Collector-Emitter Saturation Voltage 集电极发射极饱和压降 (I_C= -10mA，I_B= -1mA)	$V_{CE(sat)}$	—	—	-0.25	V
Output Voltage (on) 输出电压(导通) (V_{CC} = -5.0 V, V_B = -2.5 V, R_L =1.0KΩ)	V_{OL}	—	—	-0.2	V
Output Voltage (on) 输出电压(导通) (V_{CC} = -5.0 V, V_B = -0.25 V, R_L =1.0KΩ)	V_{OH}	-4.9	—	—	V
Input Resistor 输入电阻	R1	3.3	4.7	6.1	KΩ
Resistor Ratio 电阻比率	R1/R 2	0.8	1	1.2	

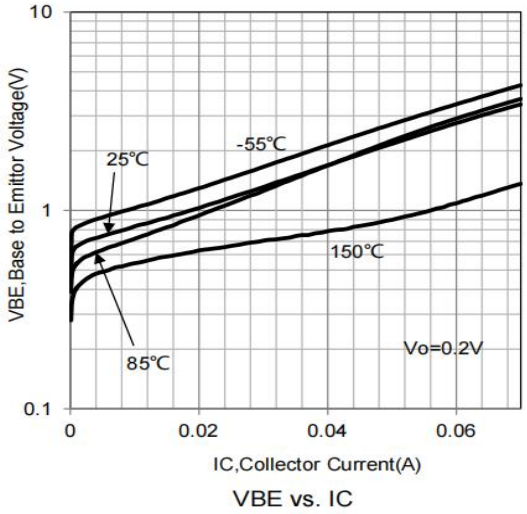
■Typical Characteristic Curve 典型特性曲线



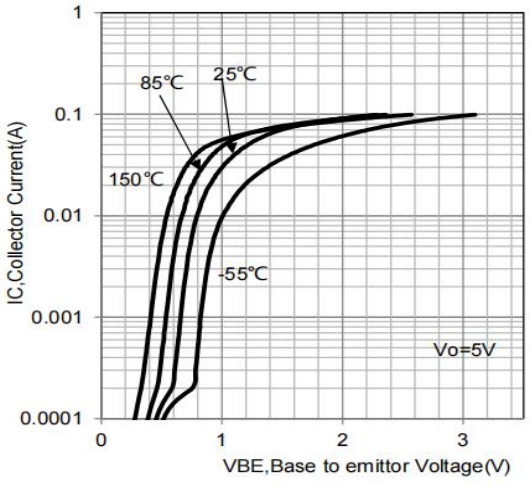
HFE vs. IC



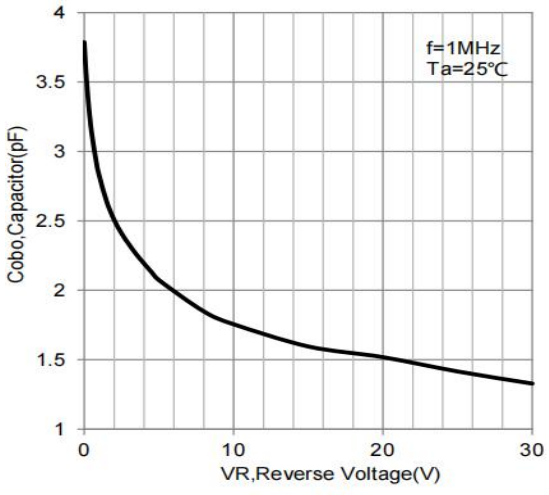
VCESAT vs. IC



VBE vs. IC

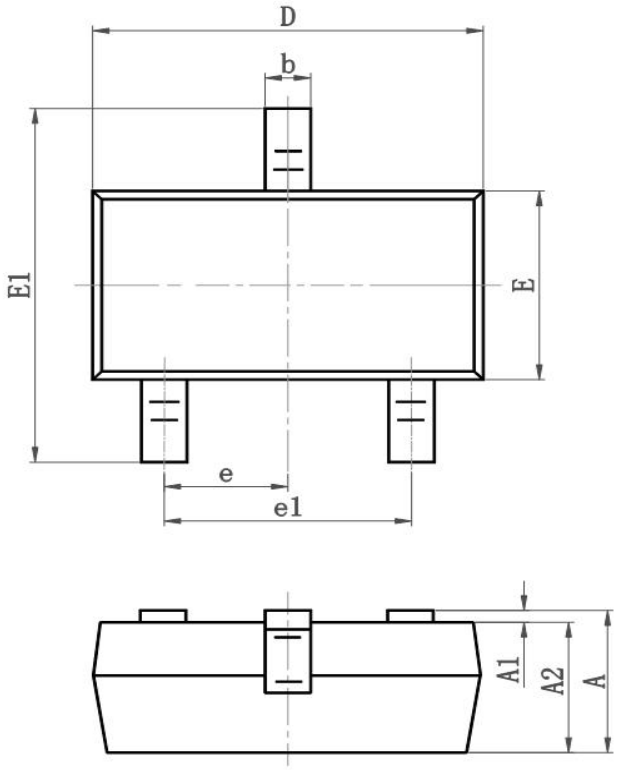


VBE vs. IC



CT vs. VR

■Dimension 外形封装尺寸



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.050	0.055
E1	2.250	2.550	0.089	0.100
e	0.900	1.00	0.035	0.039
e1	1.800	2.000	0.071	0.079
L	0.500	0.600	0.020	0.024
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°